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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Luca G. Fasoli, et al.

Title: MEMORY ARRAY INCORPORATING MEMORY CELLS ARRANGED
IN NAND STRINGS

Application No.: 10/729,843

Filed: December 5, 2003

Examiner: Luu, Pho M.

Group Art Unit: 2824

Atty. Docket No.: 023-0031

Confirmation No.: 8321

March 15, 2005

Mail Stop Amendment
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INFORMATION DISCLOSURE STATEMENT
37 C.F.R. § 1.97(b)

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Pursuant to 37 C.F.R. § 1.56, § 1.97 and § 1.98, the undersigned brings to the Examiner's attention in the above-identified application the patents, publications, applications or other information identified in the attached:

- Form(s) PTO/SB/08A (5 page(s), with copy of 4 reference(s)).
- Form(s) PTO/SB/08B (2 page(s), with copy of 20 reference(s)).
- Listing of Pending Applications (1 page(s), with copy of no application(s)).
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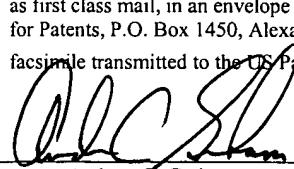
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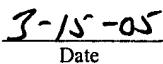
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Andrew C. Graham



Date

Respectfully submitted,



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PTO/SB/08A (Substitute for form 1449/PTO)		Attorney Docket No.: 023-0031
		Application No.: 10/729,843
O P E INFORMATION DISCLOSURE STATEMENT BY APPLICANT M A R 2 1 2 0 0 5 P A T E N T & T R A D E M A R K S		First Named Inventor: Luca G. Fasoli et al.
		Filing Date: December 5, 2003
		Group Art Unit: 2824
		Examiner Name: Pho M. Luu
Sheet 1 of 5		Date Submitted: March 15, 2005

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
	AA	4,142,176	02-27-1979	Dozier	
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	AO	JA 62-155568	07-10-1987		
	AP	JA-2001-358237	12-26-2001		
	AQ	JA-2002-280467	09-27-2002		
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PTO/SB/08A (Substitute for form 1449/PTO)	Attorney Docket No.: 023-0031
	Application No.: 10/729,843
INFORMATION DISCLOSURE STATEMENT BY APPLICANT	First Named Inventor: <i>Luca G. Fasoli et al.</i>
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	BE					
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	BI	6,188,611 B1	02-13-2001	Endoh et al.	
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	BV					
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	BX					
	BY					
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	BZ	6,515,888	02-04-2003	Johnson et al.	
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	CN					
	CO					
	CP					
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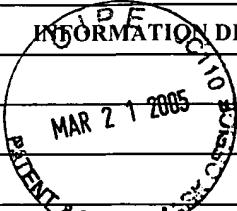
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	DE					
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NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of author (in CAPITAL LETTERS), title of article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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Examiner Signature		Date Considered	

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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	AO	SHIN, JONGSHIN, ET AL., "A New Charge Pump Without Degradation in Threshold Voltage Due to Body Effect," IEEE Journal of Solid-State Circuits, Vol. 35, No. 8, August 2000, pp. 1227-1230.	
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